<u>TOSHIBA</u>

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC125F,TC74VHC125FN,TC74VHC125FT,TC74VHC125FK TC74VHC126F,TC74VHC126FN,TC74VHC126FT,TC74VHC126FK

TC74VHC125F/FN/FT/FK Quad Bus Buffer TC74VHC126F/FN/FT/FK Quad Bus Buffer

The TC74VHC125/126 are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.

The TC74VHC125 requires the 3-state control input \overline{G} to be set high to place the output into the high impedance state, whereas the TC74VHC126 requires the control input G to be set low to place the output into high impedance.

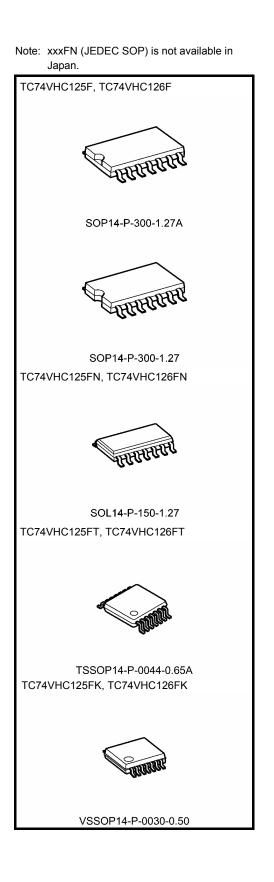
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up.

This circuit prevents device destruction due to mismatched supply and input voltages.

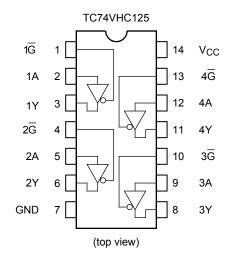
Features

- High speed: $t_{pd} = 3.8 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS125/126

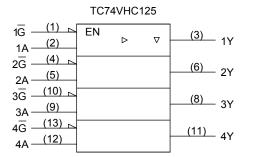
Weight	
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)



Pin Assignment



IEC Logic Symbol



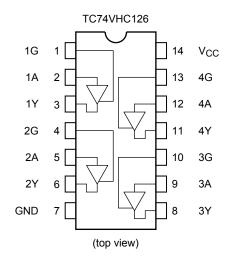
Truth Table

TC74VHC125

Inputs		Output
Ğ	А	Y
Н	Х	Z
L	L	L
L	Н	Н

X: Don't care

Z: High impedance



1G <u>(1)</u> 1A <u>(2)</u>	EN	⊳	V	(<u>3)</u> 1Y
2G <u>(4)</u> 2A <u>(5)</u>				<u>(6)</u> 2Y
3G <u>(10)</u> 3A <u>(9)</u>				<u>(8)</u> 3Y
4G <u>(13)</u> 4A <u>(12)</u>				<u>(11)</u> 4Y

TC74VHC126

Inputs		Output
G	А	Y
L	Х	Z
Н	L	L
Н	Н	Н

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	IIК	-20	mA
Output diode current	IOK	±20	mA
DC output current	IOUT	±25	mA
DC V _{cc} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	VIN	0 to 5.5	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 \pm 0.3 V)	nc/\/	
Input rise and fall time	uvuv	0 to 20 (V_{CC} = 5 \pm 0.5 V)	ns/V	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol		Test Condition		٦	Га = 25°(0	-	a = 0 85°C	Unit
	-				Min	Тур.	Max	Min	Max	
High-level input					1.50	_	_	1.50		
voltage	V _{IH}		—	3.0 to 5.5	V _{CC} × 0.7		_	V _{CC} × 0.7		V
Low-level input				2.0	_		0.50		0.50	
voltage	V _{IL}		—	3.0 to 5.5	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3	V
				2.0	1.9	2.0	_	1.9	_	
	V _{OH}		I _{OH} = -50 μA	3.0	2.9	3.0	—	2.9	—	
High-level output voltage		VIN = VIH or VIL		4.5	4.4	4.5	—	4.4	_	V
0			I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	
			I _{OH} = -8 mA	4.5	3.94	—	—	3.80	—	
		V _{IN} = V _{IH} or V _{IL}		2.0	—	0.0	0.1	—	0.1	
			$I_{OL} = 50 \ \mu A$	3.0	—	0.0	0.1	—	0.1	
Low-level output voltage	V _{OL}			4.5		0.0	0.1		0.1	V
			$I_{OL} = 4 \text{ mA}$	3.0	—	—	0.36	—	0.44	
			$I_{OL} = 8 \text{ mA}$	4.5		_	0.36		0.44	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	_	±0.25	_	±2.50	μΑ
Input leakage current	I _{IN}	$V_{IN} = 5.5 \text{ V or GND}$		0 to 5.5	_	_	±0.1	_	±1.0	μA
Quiescent supply current	ICC	V _{IN} = V _{CC} of	GND	5.5			4.0		40.0	μΑ

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max		
			3.3 ± 0.3	15	_	5.6	8.0	1.0	9.5	
Propagation delay	t _{pLH}		5.5 ± 0.5	50	_	8.1	11.5	1.0	13.0	ns
time	t _{pHL}		5.0 ± 0.5	15	_	3.8	5.5	1.0	6.5	115
			5.0 ± 0.5	50	_	5.3	7.5	1.0	8.5	
			3.3 ± 0.3	15	_	5.4	8.0	1.0	9.5	
Output anabla time	t _p ZL t _p ZH	$R_L = 1 \ k\Omega$		50		7.9	11.5	1.0	13.0	ns
Output enable time			5.0 ± 0.5	15	_	3.6	5.1	1.0	6.0	
			5.0 ± 0.5	5.0 ± 0.5	50	_	5.1	7.1	1.0	8.0
Output disable time	t _{pLZ}	$R_L = 1 \ k\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	50	_	9.5	13.2	1.0	15.0	ns
Output disable time	t _{pHZ}		5.0 ± 0.5	50	_	6.1	8.8	1.0	10.0	115
Output to output skew	t _{osLH}	(Note 1)	$\textbf{3.3}\pm\textbf{0.3}$	50	_	_	1.5	_	1.5	ns
	t _{osHL}		5.0 ± 0.5	50	—	—	1.0	_	1.0	115
Input capacitance	CIN		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}		_		_	6	_	_		pF
Power dissipation capacitance (Note 2)		TC74VHC125			14		_		рF	
	C _{PD}	TC74VHC126	TC74VHC126			15	_	_		рі

Note 1: Parameter guaranteed by design.

 $t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

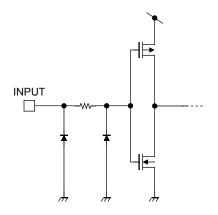
 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	-	Ta = 25°C		Unit
Characteristics	Characteristics Symbol		V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic	Max =	C _I = 50 pF	5.0	0.3	0.8	V
V _{OL}	V _{OLP}	CL = 50 pr	5.0	0.3	0.0	v
Quiet output minimum dynamic	Maria	C _L = 50 pF	5.0	-0.3	-0.8	V
V _{OL}	V _{OLV}	CL – 30 μ	5.0	-0.5	-0.0	v
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		1.5	V



Input Equivalent Circuit

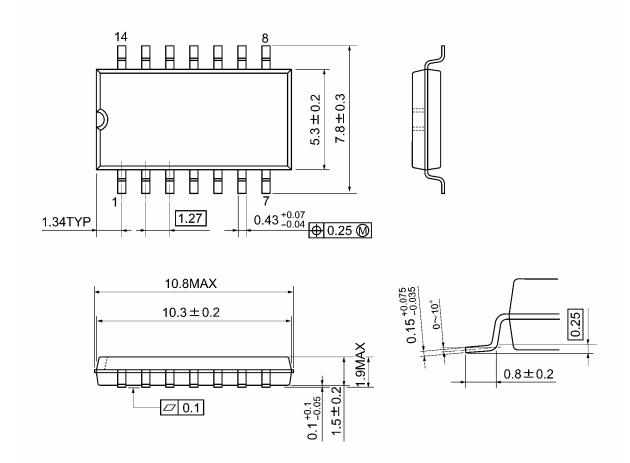




Package Dimensions

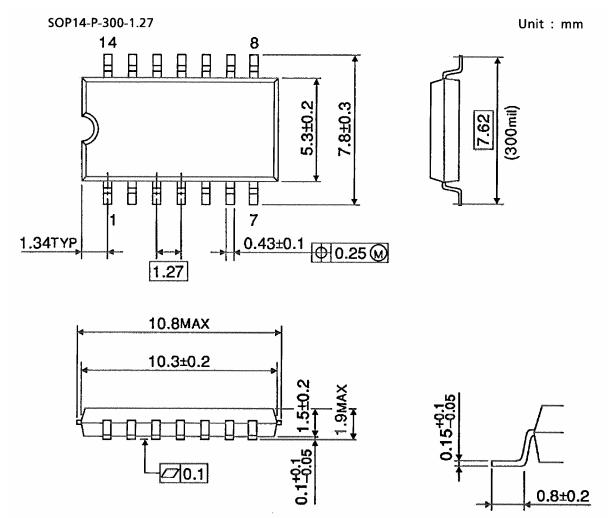
SOP14-P-300-1.27A

Unit: mm



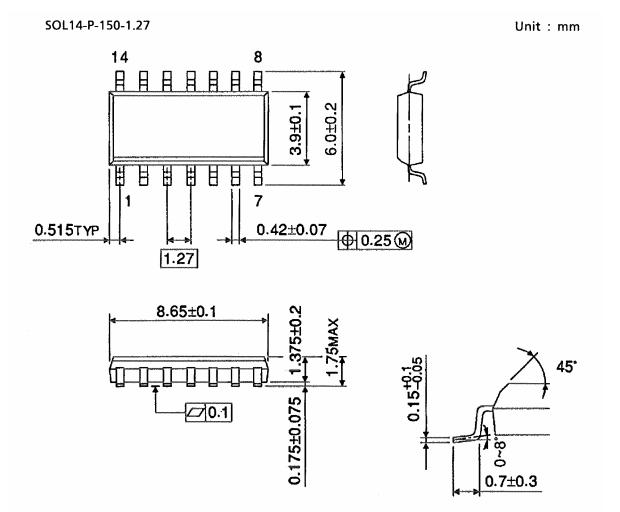
Weight: 0.18 g (typ.)

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)



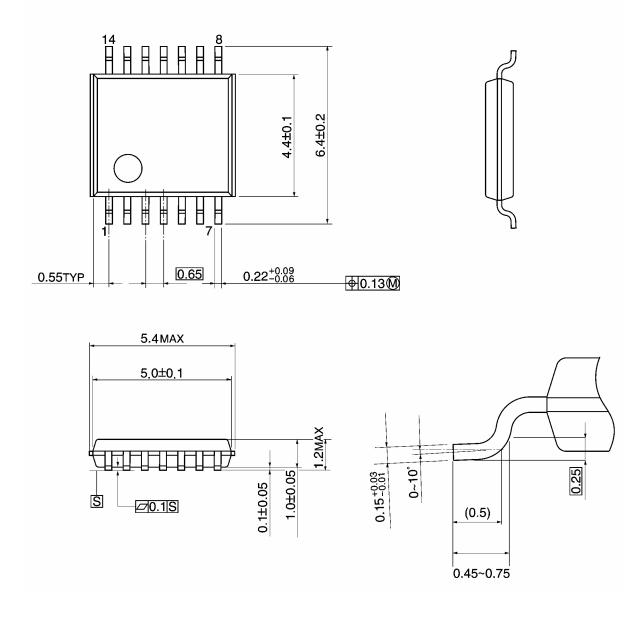
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



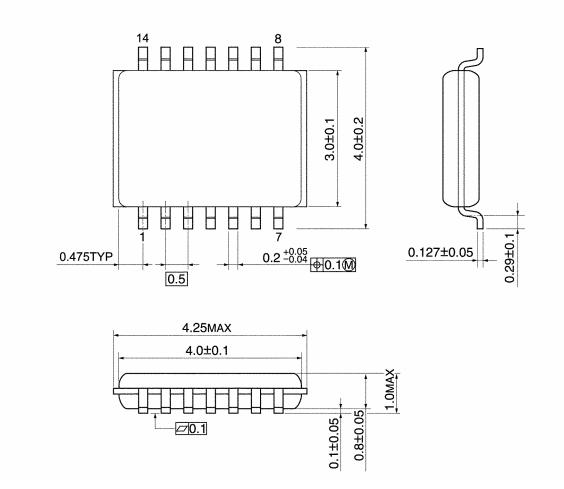
Weight: 0.06 g (typ.)

TOSHIBA

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A VSSOP14-P-0030-0.50

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